HD31235
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB GaN linear design
Instantaneous wide bandwidth
Suitable for all modulations standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	300 - 2000 MHz	
Power Output @ P1dB GCP	10 Watt Min	CW
Power Gain	40 dB Min	
Gain Flatness	4.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc Typ	30dBm/Tone, Δ = 1MHz
Harmonics	>20 dBc Typ	At rated Pout
Non Harmonics Distortions	>60 dBc	
Operating Voltage	28 - 30 VDC	
Current Consumption	3.0 Amp Max	At rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	∞ : 1	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	125 X 63 X 15 mm	Without Connectors
Weight	150 gr.	Typical Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

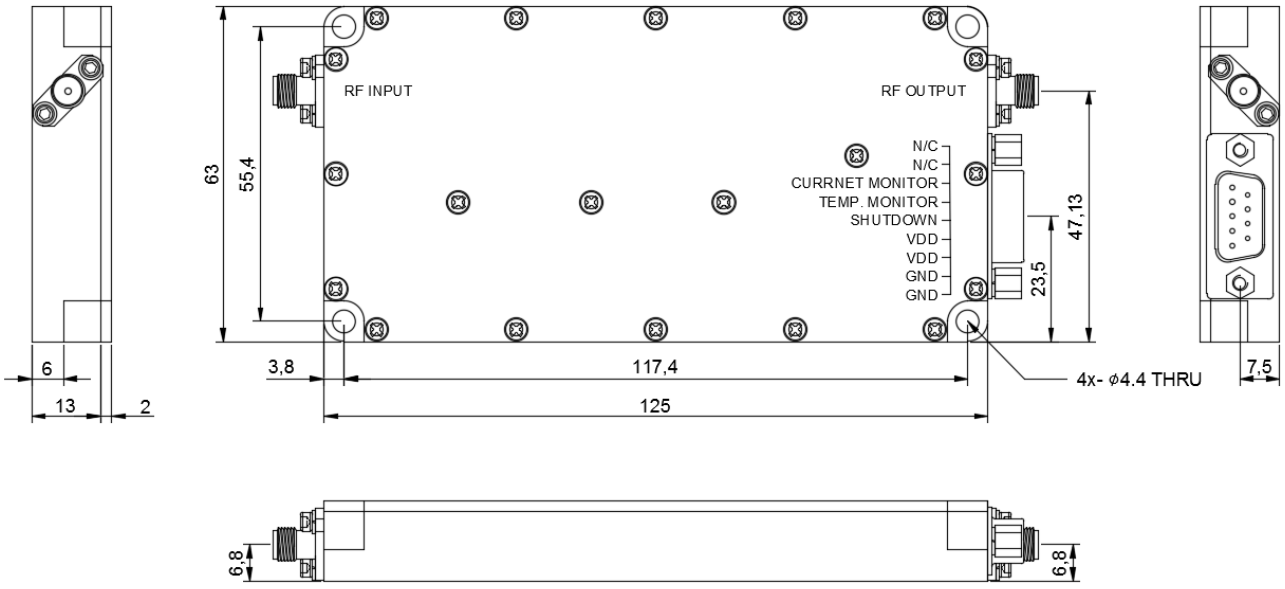
D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	N/C
2	VVA	N/C
3	CURRENT SENSOR	I_D@50mV/100mA Typ
4	TEMP SENSOR	V_T@10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
6, 7	VDD	28VDC
8, 9	GND	Ground

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OUTLINE DRAWING



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